Product data sheet

1. General description

Ultrafast power diode in a TO252 (DPAK) plastic package





2. Features and benefits

- Fast switching
- Low leakage current
- · Low reverse recovery current
- · Low thermal resistance
- · Reduces switching losses in associated MOSFET or IGBT
- · Package meets UL94 V0 which guaranteed by Epoxy Mold Compound

3. Applications

- · Active PFC in air conditioner
- · High frequency switched-mode power supplies
- Power Factor Correction (PFC)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes		Unit		
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage					V	
I _{F(AV)}	average forward current	δ = 0.5 ; square-wave pulse; $T_{mb} \le 132$ °C; Fig. 1; Fig. 2; Fig. 3				Α	
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t_p = 25 μ s; $T_{mb} \le$ 132 °C; square-wave pulse			Α		
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		95			Α
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		104.5			Α
Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.37	1.70	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.13	1.46	V
Dynamic	characteristics				,		
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}$; $V_R = 30 \text{ V}$; $dI_F/dt = 100 \text{ A/}\mu\text{s}$; $T_j = 25 \text{ °C}$; Fig. 7		-	27	-	ns

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected		к _ [4]_ А
2	K	cathode [1]		K — A 001aaa020
3	А	anode		
mb	К	mounting base; connected to cathode		

[1] It is not possible to connect to pin 2 of the TO252 package.

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing guantity	Package version	Package issue date
	Haine		method	quantity	VEISIOII	issue date
BYV8MD-650P	TO252	BYV8MD-650PJ	Reel	2500	TO252d	07-Sep-2022

7. Marking

Table 4. Marking codes

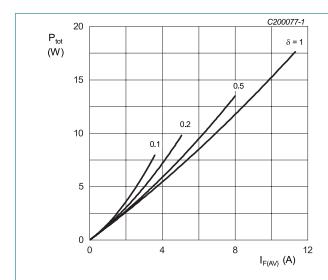
Type number	Marking codes
BYV8MD-650P	BYV8MD 650P

8. Limiting values

Table 5. Limiting values

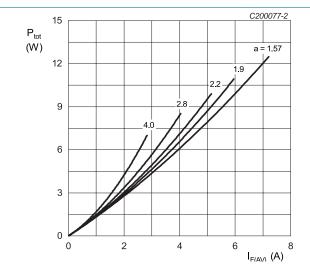
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			650	V
V_{RWM}	crest working reverse voltage			650	V
V_R	reverse voltage	DC		650	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 132$ °C; Fig. 1; Fig. 2; Fig. 3		8	А
I _{FRM}	repetitive peak forward current	δ = 0.5 ; t _p = 25 μs; T _{mb} ≤ 132 °C; square-wave pulse		16	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		95	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		104.5	А
T _{stg}	storage temperature			-65 to 175	°C
T _j	junction temperature			-65 to 175	°C



 $I_{F(AV)} = I_{F(RMS)} \times \sqrt{\delta}$ $V_o = 1.255 \text{ V; } R_s = 0.0270 \Omega$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 1.255 V; R_s = 0.0270 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

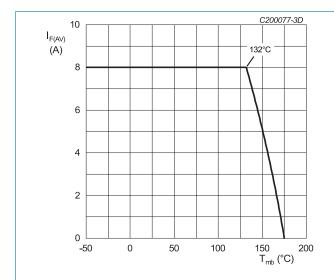


Fig. 3. Forward current as a function of mounting base temperature; maximum values

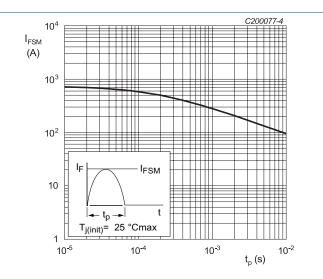


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	<u>Fig. 5</u>		-	-	3.2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	[2]	-	50	-	K/W

[2] Device mounted on an FR4 PCB, single-sided copper, tin plated and standard footprint.

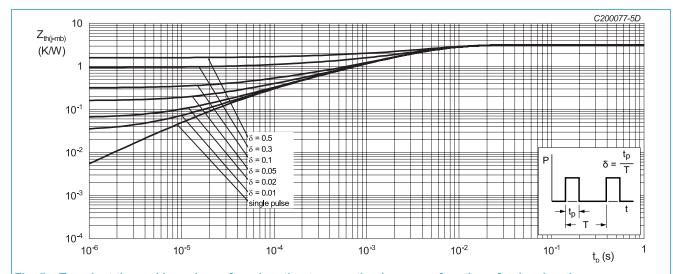
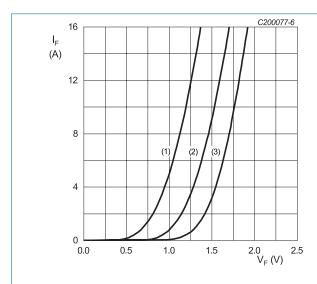


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
Static ch	aracteristics						
V_{F}	forward voltage	I _F = 8 A; T _j = 25 °C; <u>Fig. 6</u>		-	1.37	1.70	V
		I _F = 8 A; T _j = 150 °C; <u>Fig. 6</u>		-	1.13	1.46	V
I _R	reverse current	V _R = 650 V; T _j = 25 °C		-	0.27	30	μA
		V _R = 650 V; T _j = 150 °C		-	-	0.5	mA
Dynamic	characteristics				•		
Q _r	reverse charge	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	151	-	nC
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	360	-	nC
t _{rr}	reverse recovery time	$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{rr} = 0.25 \text{ A}; T_j = 25 \text{ °C}$		-	30	-	ns
		$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 100 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	27	-	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	56	-	ns
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	85	-	ns
I _{RM}	peak reverse recovery current	$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$		-	5.5	-	А
		$I_F = 8 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/}\mu\text{s};$ $T_j = 125 \text{ °C}; Fig. 7$		-	8.6	-	А
E _{as}	non-repetitive analanche energy	T _{j(init)} = 25 °C		20	-	-	mJ



 V_o = 1.255 V; R_s = 0.0270 Ω (1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values (3) T_j = 25 °C; maximum values

Fig. 6. Forward current as a function of forward voltage

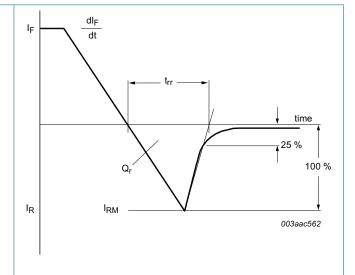
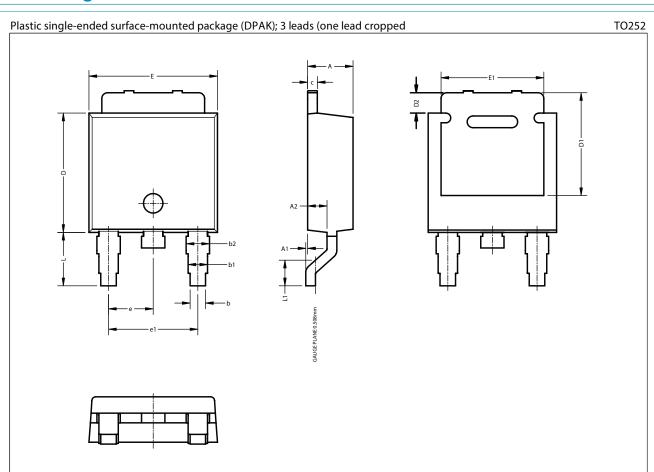


Fig. 7. Reverse recovery definitions; ramp recovery

11. Package outline



Note:

1. All dimensions do not include mold flash & gate remain and metal protrusion.

Unit	:	Α	A 1	A2	b	b1	b2	С	D	D1	D2	E	E1	е	e1	L	L1
mir mm non		2.16	0.00	0.90	0.70	0.86	1.06	0.46	5.97	5.05	0.98	6.45	5.20	2.30	4.60	2.60	1.25
		2.41	0.10	1.10	0.90	1.11	1.32	0.58	6.22	5.35	1.18	6.75				2.90	1.65

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition			
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.			
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.			
Product [short] data sheet	Production	This document contains the product specification.			

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13. Contents

1. General description	1
2. Features and benefits	1
3. Applications	1
4. Quick reference data	1
5. Pinning information	2
6. Ordering information	2
7. Marking	2
8. Limiting values	3
9. Thermal characteristics	5
10. Characteristics	6
11. Package outline	7
12. Legal information	
13. Contents	

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